

FEATURES

Collector Current: I_C=3A

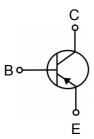
Power Dissipation of 500mw



SOT89-3L

Package Marking and Ordering Information

Product ID	Pack	Marking	Qty(PCS)
B772	SOT89-3L	B772	1000



MAXIMUM RATINGS (Ta=25 unless otherwise noted)

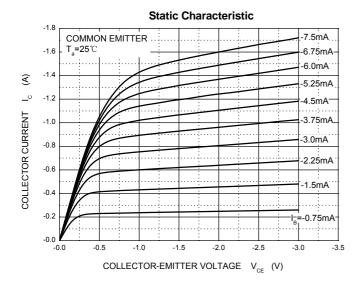
Parameter	Symbol	Limit	Unit
Collector-Base Voltage	V _{CBO}	-40	V
Collector-Emitter Voltage	V _{CEO}	-30	V
Emitter-Base Voltage	V _{EBO}	-6	V
Collector Current	I _c	-3	А
Collector Power Dissipation	P _c	500	mW
Thermal Resistance From Junction To Ambient	R _{OJA}	250	°CW
Junction Temperature	T _j	150	℃
Storage Temperature	T _{stg}	-55∼+150	℃

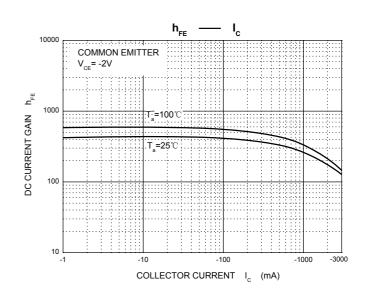


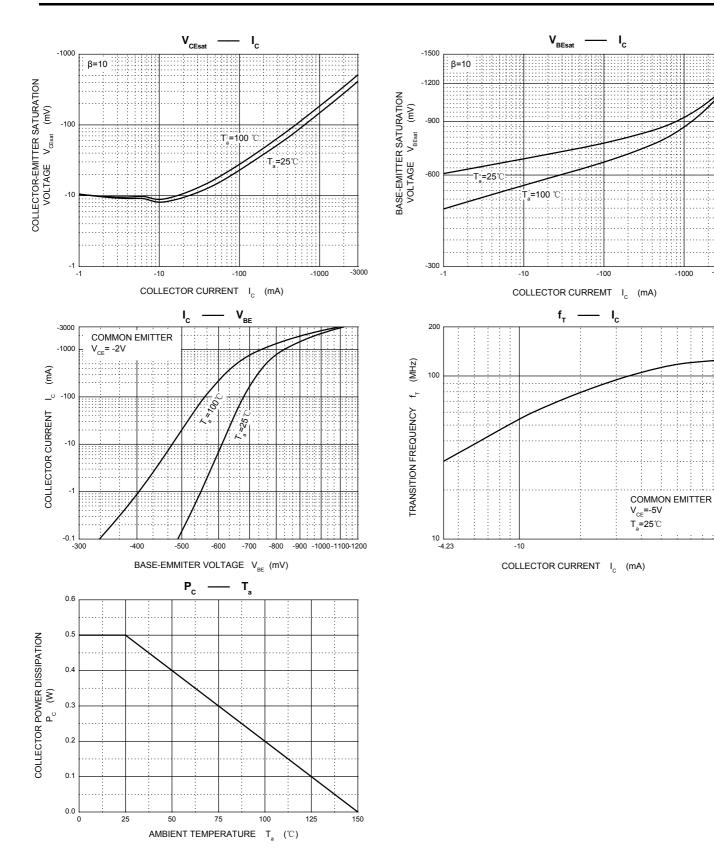
ELECTRICAL CHARACTERISTICS (Ta=25 unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Тур	Max	Unit
Collector-base breakdown voltage	V _{(BR)CBO}	I _C =-100μA ,I _E =0	-40			V
Collector-emitter breakdown voltage	V _{(BR)CEO}	I _C = -10mA , I _B =0	-30			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	I _E = -100μA,I _C =0	-6			V
Collector cut-off current	I _{CBO}	V _{CB} = -40V, I _E =0			-1	μΑ
Collector cut-off current	I _{CEO}	V _{CE} =-30V, I _B =0			-10	μΑ
Emitter cut-off current	I _{EBO}	V _{EB} =-6V, I _C =0			-1	μΑ
DC current gain	h _{FE}	V _{CE} = -2V, I _C = -1A	160		320	
Collector-emitter saturation voltage	V _{CE(sat)}	I _C =-2A, I _B = -0.2A			-0.5	V
Base-emitter saturation voltage	$V_{BE(sat)}$	I _C =-2A, I _B = -0.2A			-1.5	V
Transition frequency	f⊤	V _{CE} = -5V, I _C =-0.1A f =10MHz	50			MHz

Typical Characteristics



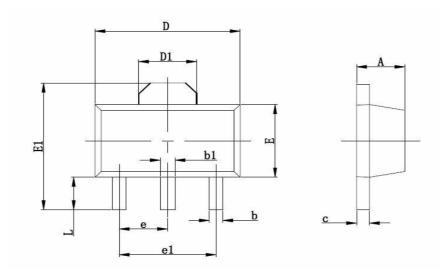




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SOT89-3L Package Outline Dimensions



Symbol	Dimensions	In Millimeters	Dimensions In Inches		
	Min	Max	Min	Max	
Α	1.400	1.600	0.055	0.063	
b	0.350	0.520	0.013	0.197	
b1	0.400	0.580	0.016	0.023	
С	0.350	0.440	0.014	0.017	
D	4.400	4.600	0.173	0.181	
D1	1.550 REF		0.061 REF		
E	2.350	2.550	0.091	0.102	
E1	3.940	4.250	0.155	0.167	
е	1.500 TYP		0.060TYP		
e1	3.000 TYP		0.118TYP		
L	0.900	1.100	0.035	0.047	

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